been present. It is possible that higher molecular weight species might have been present if higher temperatures had been achieved earlier in the vaporizations.

The presence of series 2 species probably arises from the reactivity of  $B_2Se_3$  with  $H_2O(g)$  even at low  $H_2O$ pressures. This hydrolysis reaction would be expected to introduce an oxygen contaminant also into the sample. The presence of oxygen in some species was deduced for sets of ions at masses 71, 108, and 136 as discussed previously. The presence of series 2 species  $H_2BSe_2^+$  and  $H_2B_2Se_3^+$  is assumed to be caused by parent species also bearing H atoms, probably  $H_{2^-}BSe_2(g)$  and  $H_2B_2Se_3(g)$ .

The data reported in Tables I–III indicate that the gaseous molecules  $BSe_2$  and  $B_2Se_3$  are thermally stable to 700°.

The results of this study of the boron selenides show some similarities to the studies of the vaporization of  $B_2S_3$ ;<sup>4,5,8</sup> the gaseous species observed were  $BS_2$ ,  $B_2S_3$ , and their polymers. In the earlier studies,<sup>4,5</sup> as the vaporization proceeded by heating to progressively higher temperatures, the higher molecular weight species decreased in importance leaving only  $B_2S_3(g)$ . In the study by Chen and Gilles,<sup>8</sup> the gas composition was studied as a function of the composition of the condensed B-S phase. Congruent vaporization of  $B_2S_3$ was found to produce only  $B_2S_3(g)$  and its polymers. If the sample was S rich in comparison to  $B_2S_3$ ,  $BS_2(g)$ and its polymers were found also. If the sample was S poor, then  $B_2S_2(g)$  was detected in addition to  $BS_2^+$ and  $B_2S_3^+$ . In the study of the thermal decomposition of HBS2,6,7 it was concluded that HBS2 initially lost large amounts of  $H_2S(g)$ , samples then lost gaseous polymers of  $HBX_2$ , and finally the mass spectra of boron sulfides similar to those of the earlier studies were observed.

The appearance in this study of the vaporization of  $B_2Se_3(s)$  of series 1 gaseous species may be compared

with what occurred with the similar vaporization of  $B_2S_3(s)$  by Gilles, *et al.*<sup>4,5,8</sup> The initial appearance of selenium and its polymers suggests that these  $B_2Se_3$  samples were of high selenium activity. In later stages of the vaporization of these samples, the species  $BSe_2(g)$  and  $B_2Se_3(g)$  were observed. Gilles, *et al.*, in addition to  $BS_2(g)$  and  $B_2S_3(g)$ , found gaseous polymers of  $BS_2$  and  $B_2S_3$ . If polymers of  $BSe_2$  or  $B_2Se_3$  were present, their importance was significantly less than in the case of the boron sulfides. The fact that vaporizations terminating at high temperatures led to  $B_2S_3$  and  $BSe_2$  ( $BSe_2^+$  may be a fragmentation product at the end of the vaporization) and  $B_2Se_3$  as the important gaseous molecular species shows the similarities in sulfur and selenium chemistry.

In the case of the boron selenides, the hygroscopic nature of the sample introduced H (and O) into the condensed phase. Initial stages of the vaporization showed large amounts of  $H_2Se(g)$ . In addition,  $H_2$ - $BSe_2(g)$  was observed. These results show similarities to the thermal decomposition of  $HBS_2(s)$  studied by Gilles, *et al.*,<sup>6,7</sup> in the case of  $HBS_2$ ,  $H_2S(g)$  and  $HBS_2$ (g) were observed. Further heating of the  $HBS_2$ sample gave gaseous products as found in the vaporization of  $B_2S_3(s)$ . In this study of the B–Se system, further heating of samples showing H species, see Table III, gave rise to  $B_2Se_3(g)$  just as vaporization of a sample showing only series 1 species.

Acknowledgments.—R. C. M. wishes to thank the NSF for financial support through a college teacher research participation program at the Illinois Institute of Technology. The authors wish to thank the U. S. Atomic Energy Commission for financial support of this research through Contract AT (11-1)-1029. The authors also wish to express their appreciation to Professor P. W. Gilles for the prepublication copy of an article.<sup>8</sup>

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# The Formation of Silene and Germene from the Pyrolyses of Disilane and Digermane and the Relative Insertions of Silene into Silanes

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Received October 27, 1969

The products from the pyrolysis of disilane- $d_6$  and methylsilane were silane- $d_4$  and  $CH_3SiH_2SiD_2H$ . These results demonstrate that the pyrolysis of disilane yields silene (probably singlet) and silane. The rate of insertion of silene into silicon-hydrogen bonds appears to increase greatly with an increase in the hydridic character. The pyrolysis of digermane was found similar to that of disilane.

## Introduction

We have proposed that the pyrolysis of disilane occurs via the formation of silene and silane.<sup>1</sup> This proposed mechanism (eq 1 and 2) was based on the fact

(1) E. M. Tebben and M. A. Ring, Inorg. Chem., 8, 1787 (1969).

$$Si_{2}H_{0} \longrightarrow SiH_{2} + SiH_{4}$$
(1)  

$$SiH_{2} + Si_{2}H_{6} \longrightarrow Si_{3}H_{8}$$
(2)

that the pyrolysis of disilane with low-temperature trapping yielded only silane and trisilane (eq 3).

$$2\mathrm{Si}_{2}\mathrm{H}_{6} \longrightarrow \mathrm{Si}\mathrm{H}_{4} + \mathrm{Si}_{3}\mathrm{H}_{8} \tag{3}$$

In this paper we report our results on the trapping of silene- $d_2$  by methylsilane and on relative rates of silene insertion into silanes. We also report our results on the pyrolysis of digermane.

#### Results

The results listed below were obtained in flow systems which contained a cold trap which set the pressure of the reactants and which condensed the volatile products except silane or germane which are stable at the reaction temperatures.

1. Thermal Reaction of  $Si_2D_6$  with  $CH_3SiH_3$ .—The products from the pyrolysis of disilane- $d_6$  in the presence of excess (~6.7:1) methylsilane at 375° were silane- $d_4$ and  $CH_3SiH_2SiD_2H$ . The very small hydrogen fraction obtained was all D<sub>2</sub>. The absence of HD demonstrates that deuterium atoms were not present since they would abstract hydrogen atoms from methylsilane. Thus the initial step in the pyrolysis of disilane must be either the formation of silyl radicals or the formation of silene and silane (eq 1). The formation of  $CH_3SiH_2$ - $SiD_2H$  clearly demonstrates that the reactive species from the disilane pyrolysis is the silene radical (methylsilane is stable below 500°).<sup>2</sup>

The silene radical could be formed either from eq 1 or from the initial formation of silyl radicals followed by the conversion of silyl to silene.<sup>3</sup> The conversion of silyl radicals could occur by a decomposition to silene and deuterium which we can eliminate (no HD) or by a deuterium abstraction reaction. In this case, the abstraction reactions would be

$$SiD_3 + SiD_3 \longrightarrow SiD_4 + SiD_2$$
 (4)

$$SiD_3 + Si_2D_6 \longrightarrow SiD_4 + Si_2D_5$$
 (5)

$$SiD_3 + CH_3SiH_3 \longrightarrow SiD_3H + CH_3SiH_2$$
 (6)

From concentration and even activation energy<sup>4</sup> considerations, the relative rates for these three reactions must be eq  $6 > eq 5 \gg eq 4$ . Since silane- $d_3$  was not observed, we can eliminate reaction 6 and thus also reaction 4. Therefore, we can conclude that silene- $d_2$ was produced according to eq 1 which is the initial decomposition step in the pyrolysis of disilane.

2. Thermal Reaction of  $Si_2H_6$  with  $(CH_3)_2SiH_2$ .— The products from the pyrolysis of disilane in the presence of dimethylsilane  $\{[Si_2H_6]/[(CH_3)_2SiH_2] \cong 0.93/1.00\}$  at 412° were 1,1-dimethyldisilane and trisilane in a 1.44:1 ratio. This experiment measured the relative rate of silene insertion into dimethylsilane and disilane. With a correction for steric factors, this result demonstrates that insertion into the siliconhydrogen bond of dimethylsilane was favored over that of disilane by about 7:1. This result suggests that silene acts as a electrophilic reagent.

3. Thermal Reaction of  $Si_2H_6$  with  $ClSiH_3$ .—The silene insertion product from the pyrolysis of disilane at 400° in the presence of a small excess of chlorosilane

was trisilane with no evidence for the formation of chlorodisilane. This result confirms the fact that silene acts as an electrophile during insertion reactions into silicon-hydrogen bonds.

4. Pyrolysis of Digermane.—The results from the pyrolysis of digermane are listed in Table I. These

TABLE I Pyrolysis of Digermane

	$Ge_2H_6$				
Temp,	consumed,	Amt	of products, n	1mol	Time,
°C	mmol	GeH4	Ge3Hs	$\mathbf{H}_2$	hr
230	0.01	0.004	0.004		3
240	0.08	0.04	0.04		3
240	0.05	0.02	0.02		3
250	0.06	0.03	0.01	0.005	2.5

results show that the pyrolysis of digermane (eq 7) is

$$2\mathrm{Ge}_{2}\mathrm{H}_{6} \longrightarrow \mathrm{GeH}_{4} + \mathrm{Ge}_{3}\mathrm{H}_{8} \tag{7}$$

similar to that of disilane. The low quantity of hydrogen produced demonstrates that hydrogen atoms were not formed in the initial decomposition.

5. Thermal Reaction of  $Ge_2H_6$  with  $C_2H_5GeD_3$ .— The products from the pyrolysis of digermane in the presence of ethylgermane- $d_3$  at 280° were germane, trigermane, and ethyldigermanes while diethyldigermanes were not observed. These results strongly argue that digermane decomposes into germene and germane (eq 8). If digermane had decomposed into germyl

$$Ge_2H_6 \longrightarrow GeH_2 + GeH_4$$
 (8)

radicals, reaction 8 should have produced germane- $d_1$  and a diethyldigermane.

## Discussion

1. Pyrolysis of Disilane and Digermane.—It is well known that disilane is thermally less stable than ethane or peralkyl- or peraryldisilanes.<sup>5</sup> Ethane and hexamethyldisilane decompose by carbon-carbon<sup>6</sup> or silicon-silicon<sup>7</sup> bond fission with activation energies of 89.5 and 67 kcal/mol, respectively. Though the silicon-silicon bond energy in disilane is open to question, the best value appears to be 81 kcal/mol.<sup>8</sup> Therefore, if disilane were to decompose into silvl radicals, the activation energy would be about 80 kcal/mol and disilane would be essentially as thermally stable as ethane and the organodisilanes. Thus, the different decomposition mode found for disilane explains its lower thermal stability. We have estimated that the activation energy for this process is 57 kcal/mol. This value is based on an A factor of 16 and data from the pyrolysis of disilane reported by Tebben and Ring.<sup>1</sup> It is also of interest that the pyrolysis of digermane appears to proceed through the formation of germene and germane.

The formation of silene and silane from disilane suggests that the activated complex has a bridging hydro-

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gen atom similar to what exists in diborane. Since silicon has low-lying vacant "d" orbitals available for bonding, the apparent formation of the bridged intermediate in place of silicon-silicon bond fission seems reasonable. In ethane, with no low-lying vacant orbitals, the formation of such an intermediate must require a higher energy than simple carbon-carbon bond fission. It is interesting that methyl groups do not form bridged intermediates in hexamethyldisilane. Again, this is reminiscent of diborane where methyl groups do not form stable bridged compounds.

2. Silene Insertion Reactions.—The fact that silene insertion into methylsilane occurred without any scrambling of products strongly argues that the silene was in its singlet state. If it were triplet silene, hydrogen extraction would be expected followed by random radical recombinations. It is not known what the ground state of silene is, but singlet silene<sup>9</sup> has been observed spectroscopically from the flash photolysis of phenylsilane and from the flash discharge of silane.

If silene is in its singlet state in our reactions, then its selectivity toward insertion into silicon-hydrogen bonds greatly exceeds the selectivity observed for singlet carbene insertion into carbon-hydrogen bonds. This high selectivity could be due to the nature of silene compared to carbene or due to a greater polarizability of silicon-hydrogen bonds compared to carbon-hydrogen bonds.

#### Experimental Section

All pyrolysis experiments were carried out in flow systems previously described<sup>1,2</sup> which contained an automatic Toepler pump and a cold trap.

The silicon hydrides and ethylgermane- $d_3$  were prepared by the lithium aluminum hydride or deuteride reduction of the corresponding chloro compounds. Digermane was prepared from the electric discharge decomposition of germane. The purity of disilane, disilane- $d_5$ , and digermane was verified by a mass spectrum which consisted only of ions with a heavy-atom skeleton— $E_2H(D)_{5-x}^+$  and  $EH(D)_{3-x}^+$  (E = Si, Ge), whose infrared spectrum and vapor pressure demonstrated that silane or germane was absent. The purity of the methylsilanes and ethylgermane- $d_3$  was verified in the same manner. The infrared spectrum of disilane- $d_6$  and ethylgermane- $d_3$  demonstrated that only a few per cent of the silicon-hydrogen or germanium-hydrogen bonds were not deuterated.

1. Thermal Reaction of  $Si_2D_6$  with  $CH_8SiH_8$ .—Disilane- $d_6$  (0.725 mmol) and methylsilane (1.88 mmol) were pyrolyzed at 375° for 30 hr. The product trap was at -95° (toluene slush) where the vapor pressures were 12 and 83 mm, respectively. The products and reactants were separated by trap to trap distillations. The fraction passing a -196° trap (0.02 mmol) was identified as  $D_2$  by a mass spectrum.

The product condensed in the  $-196^{\circ}$  trap was silane- $d_4$  (0.372 mmol). The infrared spectrum demonstrated that only a trace of silane- $d_3^{10}$  was present while strong bands from silane- $d_2^{10}$  and  $-d_1^{11}$  were not observed. The fraction condensed in the  $-160^{\circ}$  trap (1.88 mmol) was identified by an infrared spectrum and a mass spectrum as a mixture of methylsilane and disilane- $d_6$  in a 4.26:1 ratio. This ratio was determined from the mass spectrum which was compared to the mass spectrum of an analytical mixture. The fraction which condensed in the  $-112^{\circ}$  trap was

 $CH_3SiH_2SiD_2H$  (0.278 mmol) while the fraction condensed in the  $-95^{\circ}$  trap (0.005 mmol) was too small to identify completely but appeared to be  $CH_3SiH_2SiD_2H$ . The identification of  $CH_3SiH_2$ -SiD<sub>2</sub>H was based on the following observations.

(1) The proton nmr spectrum (10%) in carbon tetrachloride consisted of three sets of resonances with  $\delta$  values of 3.50, 3.00, and 0.17 ppm (external standard) with relative intensities 1.96:1.00:3.02. These were assigned to -SiH2, D2SiH-, and  $H_3C-$ . For methyldisilane (18% in cyclohexane) these resonances were observed at  $\delta$  3.83, 3.33, and 0.40 ppm.<sup>12</sup> The resonance at  $\delta$  3.50 ppm was complex as expected while that of the methyl group was a well-resolved triplet with  $J_{H-H'} = 4.6$  cps compared to 4.2 cps reported for methyldisilane. The resonance at 3.00 ppm was a broadened triplet with  $J_{H-H'} = 2.7$  cps compared to the well-resolved triplet in methyldisilane with  $J_{H-H'} =$ 2.5 cps. The values of  $J_{H-D}$  in SiH<sub>3</sub>D and SiHD<sub>3</sub> are 0.427 and 0.412 cps<sup>13</sup> and it seems reasonable to expect similar values for  $J_{H-D}$  in  $CH_3SiH_2SiD_2H$ . If  $J_{H-D}$  in  $CH_3SiH_2SiD_2H$  is about 0.4 cps, the D<sub>2</sub>SiH- resonance would be a broadened triplet with an expected  $J_{H-H'}$  of about 2.5 cps.

(2) The mass spectrum of methyldisilane has a strong parent peak at m/e 76 with much weaker peaks at m/e 77 and 78 due to <sup>29</sup>Si and <sup>30</sup>Si. As expected, our sample had a strong parent peak at m/e 78 and much weaker peaks at m/e 79 and 80 (see Table II).

TABLE II MASS SPECTRUM OF  $CH_3Si_2H_5$  and  $CH_3SiH_2SiD_2H$ 

	m/e										
	80	79	78	77	76	75	74	73			
$CH_3SiH_2SiD_2H$ $CH_3Si_2H_6^{13}$	4.2	10	$\begin{array}{c} 64 \\ 2.7 \end{array}$	$37 \\ 5.6$	$31 \\ 32.1$	27 22. <b>7</b>	$rac{21}{25.7}$	$\frac{27}{13.5}$			

(3) The infrared spectrum consisted of the following absorptions in cm<sup>-1</sup>: 2970 (m), 2150 (vs), 1560 (s), 1270 (m), 940 (s), 885 (vs), 790 (vs), 715 (s), 665 (vs), 630 (m), and 555 (m). The intensity of the silicon-hydrogen stretching frequency was stronger than the silicon-deuterium stretching frequency which would be expected for CH<sub>3</sub>SiH<sub>2</sub>SiD<sub>2</sub>H but not for CH<sub>3</sub>SiH<sub>2</sub>SiD<sub>3</sub>.

2. Thermal Reaction of  $Si_2H_6$  with  $(CH_3)_2SiH_2$ .—Disilane and dimethylsilane (1.23 mmol each) were pyrolyzed in a flow system at 412° for 24 hr. The product trap was at  $-78^{\circ}$  (Dry Ice-2-propanol) where the vapor pressures were 28 and 30 mm, respectively. The products were separated by trap to trap distillations. Hydrogen (0.30 mmol) passed the  $-196^{\circ}$  trap. The fraction condensed in the  $-196^{\circ}$  trap was identified as silane (0.60 mmol) by an infrared spectrum. The fraction condensed in the  $-160^{\circ}$  trap was dimethylsilane (0.84 mmol). The fraction condensed in the  $-78^{\circ}$  trap (0.66 mmol) was a mixture of 1,1-dimethylsilane and trisilane in a ratio of 1.44:1. This mixture was identified by an infrared spectrum which contained only those bands reported for 1,1-dimethyldisilane<sup>14</sup> and trisilane<sup>15</sup> and an nmr spectrum which was a composition of that reported for 1,1-dimethyldisilane<sup>14</sup> and trisilane.<sup>16</sup> The ratio was determined from the relative intensities of the silicon-hydrogen absorptions and the carbon-hydrogen absorptions. The fraction condensed in the  $-45^{\circ}$  trap was a trace of tetrasilane.

In similar experiments the ratio of 1,1-dimethyldisilane to trisilane was 2.1 and 2.8 for pyrolysis at 410 and 400°, respectively.

In a separate control experiment, dimethylsilane was pyrolyzed in the same flow system at 420° for 24 hr with the product trap at  $-78^{\circ}$  without any decomposition.

3. Thermal Reaction of  $Si_2H_6$  with  $ClSiH_8$ .—The pyrolysis of a disilane-chlorosilane mixture was conducted at 400° for 7 hr with the product trap held at  $-95^\circ$ . The products were silane,

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trisilane, and some dichlorosilane. Chlorodisilane<sup>17</sup> was not obtained.

4. Pyrolysis of Digermane.—The pyrolysis of digermane was examined in the same flow apparatus as previously described.<sup>1</sup> The product trap was set at  $-45^{\circ}$ . Germane was found in the  $-196^{\circ}$  trap, digermane was found in the  $-130^{\circ}$  trap having passed a  $-95^{\circ}$  trap, and trigermane passed a  $-36^{\circ}$  trap and condensed in a  $-63^{\circ}$  trap. The trigermane was identified by a mass spectrum which contained only peaks from the ions of heavy-atom skeletons,  $Ge_{3}^{+}$  (25.5%),  $Ge_{2}^{+}$  (64.3%), and  $Ge^{+}$ (10.2%). The infrared spectrum was identical with that reported by MacKay and Robinson<sup>18</sup> while the strong 812-cm<sup>-1</sup> absorption from germane<sup>19</sup> and the strong 750-cm<sup>-1</sup> absorption from digermane<sup>20</sup> were absent.

5. Thermal Reaction of  $Ge_2H_6$  with  $C_2H_5GeD_3.--Digermane (0.41 mmol) and ethylgermane-<math display="inline">d_8$  (1.80 mmol) were pyrolyzed at

280° for 24 hr with the product trap set at  $-63^{\circ}$ . Under the conditions, very small quantities of products were obtained. The product fraction condensed in the  $-196^{\circ}$  trap was identified by infrared and mass spectra to be germane. The strong 706-cm<sup>-1</sup> band of germane- $d_1^{21}$  was absent from the infrared spectrum. The fraction condensed at  $-95^{\circ}$  was the unreacted ethylgermane- $d_3$ . The fraction which passed the  $-45^{\circ}$  trap and condensed in the  $-63^{\circ}$  was a mixture of ethyldigermanes and trigermane. The mass spectrum of this mixture consisted of ions with the following heavy-atom skeletons: Ge<sub>3</sub><sup>+</sup> (7.2), C<sub>2</sub>Ge<sub>2</sub><sup>+</sup> (22.2), Ge<sub>2</sub><sup>+</sup> (100), C<sub>2</sub>Ge<sup>+</sup> (68.9), and Ge<sup>+</sup> (62.2). No diethyldigermanes were observed.

In a control experiment, no products were observed from the 5-hr pyrolysis of ethylgermane- $d_3$  at  $320^{\circ}$  with the trap set at  $-54^{\circ}$ , which gave a higher reaction pressure than with the bath set at  $-63^{\circ}$ .

Acknowledgment.—The authors are indebted to the U. S. Army Research Office (Durham) for financial support.

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CONTRIBUTION FROM MALLINCKRODT CHEMICAL LABORATORY HARVARD UNIVERSITY, CAMBRIDGE, MASSACHUSETTS 02138

# The Direct Synthesis of Organic Derivatives of Silicon Using Nonhalogenated Organic Compounds

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Received December 24, 1969

Some trialkoxysilanes,  $(RO)_3SiH$  ( $R = CH_3$ ,  $C_2H_5$ ,  $n-C_3H_7$ ,  $i-C_4H_9$ ), and tetraalkoxysilanes were prepared directly by the reactions of the appropriate primary alcohol with a silicon-copper contact mixture. Similar attempts with secondary and tertiary alcohols, ethers, and secondary amines gave no silicon-containing products.

#### Introduction

With the discovery in 1940 of the direct synthesis, the problems of large-scale production of organosilicon halides were solved, in large part. The first paper described the high-temperature reaction of chloromethane with elemental silicon, in the presence of a copper catalyst in a flow system, from which mixtures of methylchlorosilanes were obtained.<sup>2</sup> This process was discovered independently and later by two other chemists.<sup>3</sup> Since that time, much effort has been spent on attempts to elucidate the mechanism of this process and also to extend its application. The scope of the direct synthesis has now been successfully widened to include the reactions of: (a) other aliphatic chloro compounds, e.g., *n*-propyl, isopropyl, etc.;<sup>4-8</sup> (b) aromatic halo compounds, e.g., bromobenzene and chloro-

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benzene;<sup>9–11</sup> (c) olefinic chloro compounds, *e.g.*, allyl chloride;<sup>12–15</sup> (d) polyfunctional compounds, *e.g.*, dichloroalkanes;<sup>16–21</sup> (e) silicon-containing aliphatic chlorides, *e.g.*,  $\gamma$ -chloropropylmethyldichlorosilane;<sup>22–28</sup>

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